RELIABILITY REPORT

FOR

MAX919Exx

PLASTIC ENCAPSULATED DEVICES

July 21, 2003

MAXIM INTEGRATED PRODUCTS

120 SAN GABRIEL DR.

SUNNYVALE, CA 94086

Written by

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Conclusion

The MAX919 successfully meets the quality and reliability standards required of all Maxim products. In addition, Maxim's continuous reliability monitoring program ensures that all outgoing product will continue to meet Maxim's quality and reliability standards.

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I. Device Description

A. General

The MAX920 nanopower comparator in a space-saving SOT23 package features Beyond-the-Rails™ inputs and is guaranteed to operate down to +1.8V. The MAX919 requires just 380nA of supply current. Thes features make the MAX919 ideal for all 2-cell battery applications, including monitoring/management.

The unique design of the output stage limits supply-current surges while switching, virtually eliminating the supply glitches typical of many other comparators. This design also minimizes overall power consumption under dynamic conditions. The MAX919 has a push/pull output stage that sinks and sources current. Large internal output drivers allow Rail-to-Rail® output swing with loads up to 8mA

B. Absolute Maximum Ratings

<u>ltem</u>	Rating
Supply Voltage (VCC to VEE) Voltage Inputs (IN+, IN-, REF) Output Voltage Output Current Output Short-Circuit Duration Continuous Power Dissipation (TA = +70°C)	+6V (VEE - 0.3V) to (VCC + 0.3V) (VEE - 0.3V) to +6V ±50mA 10sec
Operating Temperature Range	-40°C to +85°C
Storage Temperature Range	-65°C to +150°C
Lead Temperature (soldering, 10sec)	+300°C
Continuous Power Dissipation (TA = +70°C)	
5-Pin SOT23	571mW
8-Pin SO	471mW
Derates above +70°C	
5-Pin SOT23	7.31W/°C
8-Pin SO	5.88W/°C

II. Manufacturing Information

A. Description/Function: SOT23, 1.8V, Nanopower, Beyond-the-Rails Comparators

B. Process: S12 (Standard 1.2 micron silicon gate CMOS)

C. Number of Device Transistors: 98

D. Fabrication Location: Oregon or California, USA

E. Assembly Location: Malaysia, Thailand or Philippines

F. Date of Initial Production: July, 1998

III. Packaging Information

5-Pin SOT23 A. Package Type: 8-Pin NSO B. Lead Frame: Copper Copper C. Lead Finish: Solder Plate Solder Plate D. Die Attach: Silver-filled Epoxy Silver-filled Epoxy E. Bondwire: Gold (1.0 mil dia.) Gold (1.0 mil dia.) F. Mold Material: Epoxy with silica filler Epoxy with silica filler G. Assembly Diagram: # 05-1501-0158 # 05-1501-0157

H. Flammability Rating: Class UL94-V0 Class UL94-V0

I. Classification of Moisture Sensitivity

per JEDEC standard JESD22-112: Level 1 Level 1

IV. Die Information

A. Dimensions: 56 x 38 mils

B. Passivation: Si₃N₄/SiO₂ (Silicon nitride/ Silicon dioxide)

C. Interconnect: Aluminum/Si (Si = 1%)

D. Backside Metallization: None

E. Minimum Metal Width: 1.2 microns (as drawn)

F. Minimum Metal Spacing: 1.2 microns (as drawn)

G. Bondpad Dimensions: 5 mil. Sq.

H. Isolation Dielectric: SiO₂

I. Die Separation Method: Wafer Saw

V. Quality Assurance Information

A. Quality Assurance Contacts: Jim Pedicord (Reliability Lab Manager)

Bryan Preeshl (Executive Director) Kenneth Huening (Vice President)

B. Outgoing Inspection Level: 0.1% for all electrical parameters guaranteed by the Datasheet.

0.1% For all Visual Defects.

C. Observed Outgoing Defect Rate: < 50 ppm

D. Sampling Plan: Mil-Std-105D

VI. Reliability Evaluation

A. Accelerated Life Test

The results of the 135°Cbiased (static) life test are shown in **Table 1**. Using these results, the Failure Rate (λ) is calculated as follows:

$$\lambda = \underbrace{\frac{1}{\text{MTTF}}}_{} = \underbrace{\frac{1.83}{192 \times 4389 \times 80 \times 2}}_{} \text{(Chi square value for MTTF upper limit)}$$

$$\underbrace{\text{Temperature Acceleration factor assuming an activation energy of } 0.8eV$$

$$\lambda = 13.57 \times 10^{-9}$$

 λ = 13.57 F.I.T. (60% confidence level @ 25°C)

This low failure rate represents data collected from Maxim's reliability monitor program. In addition to routine production Burn-In, Maxim pulls a sample from every fabrication process three times per week and subjects it to an extended Burn-In prior to shipment to ensure its reliability. The reliability control level for each lot to be shipped as standard product is 59 F.I.T. at a 60% confidence level, which equates to 3 failures in an 80 piece sample. Maxim performs failure analysis on any lot that exceeds this reliability control level. Attached Burn-In Schematic (Spec. # 06-5415) shows the static Burn-In circuit. Maxim also performs quarterly 1000 hour life test monitors. This data is published in the Product Reliability Report (RR-1M).

B. Moisture Resistance Tests

Maxim pulls pressure pot samples from every assembly process three times per week. Each lot sample must meet an LTPD = 20 or less before shipment as standard product. Additionally, the industry standard 85°C/85%RH testing is done per generic device/package family once a quarter.

C. E.S.D. and Latch-Up Testing

The CM44-2 die type has been found to have all pins able to withstand a transient pulse of ± 2500 V, per Mil-Std-883 Method 3015 (reference attached ESD Test Circuit). Latch-Up testing has shown that this device withstands a current of ± 250 mA.

Table 1 Reliability Evaluation Test Results

MAX919Exx

TEST ITEM	TEST CONDITION	FAILURE IDENTIFICATION	PACKAGE	SAMPLE SIZE	NUMBER OF FAILURES	
Static Life Test (Note 1)						
	Ta = 135°C Biased Time = 192 hrs.	DC Parameters & functionality		80	0	
Moisture Testi	ng (Note 2)					
Pressure Pot	Ta = 121°C P = 15 psi. RH= 100% Time = 168hrs.	DC Parameters & functionality	SOT23 NSO	77 77	0	
85/85	Ta = 85°C RH = 85% Biased Time = 1000hrs.	DC Parameters & functionality		77	0	
Mechanical Str	ress (Note 2)					
Temperature Cycle	-65°C/150°C 1000 Cycles Method 1010	DC Parameters & functionality		77	0	

Note 1: Life Test Data may represent plastic DIP qualification lots. Note 2: Generic Package/Process data

Attachment #1

TABLE II. Pin combination to be tested. 1/2/

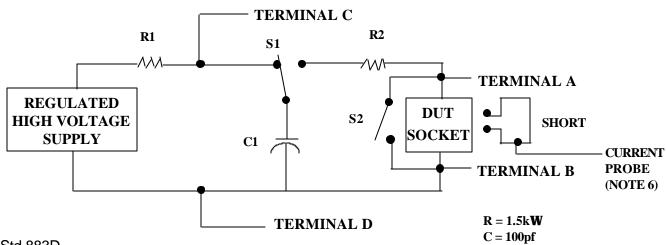
	Terminal A (Each pin individually connected to terminal A with the other floating)	Terminal B (The common combination of all like-named pins connected to terminal B)		
1.	All pins except V _{PS1} 3/	All V _{PS1} pins		
2.	All input and output pins	All other input-output pins		

- 1/ Table II is restated in narrative form in 3.4 below.
- 2/ No connects are not to be tested.
- 3/ Repeat pin combination I for each named Power supply and for ground

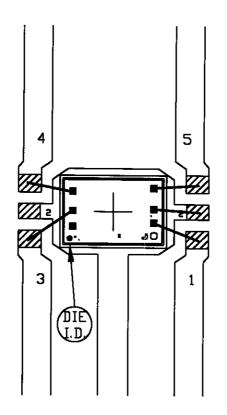
(e.g., where V_{PS1} is V_{DD} , V_{CC} , V_{SS} , V_{BB} , GND, $+V_{S}$, $-V_{S}$, V_{REF} , etc).

3.4 Pin combinations to be tested.

- a. Each pin individually connected to terminal A with respect to the device ground pin(s) connected to terminal B. All pins except the one being tested and the ground pin(s) shall be open.
- b. Each pin individually connected to terminal A with respect to each different set of a combination of all named power supply pins (e.g., \(\lambda_{S1} \), or \(\lambda_{S2} \) or \(\lambda_{S3} \) or \(\lambda_{CC1} \), or \(\lambda_{CC2} \)) connected to terminal B. All pins except the one being tested and the power supply pin or set of pins shall be open.
- c. Each input and each output individually connected to terminal A with respect to a combination of all the other input and output pins connected to terminal B. All pins except the input or output pin being tested and the combination of all the other input and output pins shall be open.



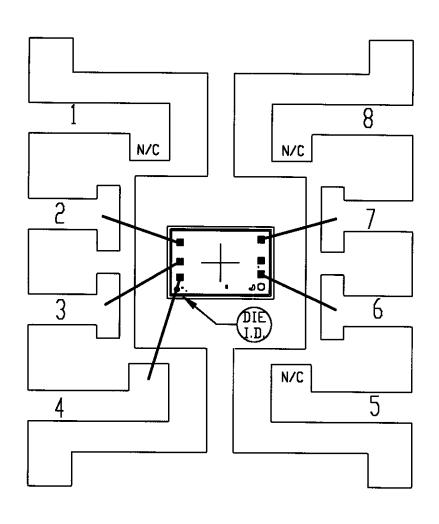
Mil Std 883D Method 3015.7 Notice 8



Ø- BONDING AREA

NOTE: CAVITY DOWN

PKG.CODE: U5-1		APPROVALS	DATE	NIXIXI	/VI
CAV./PAD SIZE:	PKG.			BUILDSHEET NUMBER:	REV.:
64X45	DESIGN			05-1501-0158	A



bkg'code: 28-5		APPROVALS	DATE	/VI/IXI	111
CAV./PAD SIZE:	PKG.	· · · · · · · · · · · · · · · · · · ·		BUILDSHEET NUMBER:	REV.:
90 X 90	DESIGN			05-1501-0157	

